

FERRITE MULTILAYER CHIP INDUCTOR

PRODUCT SERIES

160808 SERIES

Part No.	Inductance (μH)	Q Min.	L,Q Test Frequency (MHz)	Self-Resonant Frequency Min. Nominal (MHz)	DC Resistance Max. Nominal (Ω)	Rated Current Max. (mA)
CMI160808V47N	0.047±20%	25	50	260	0.30	50
CMI160808V68N	0.068±20%	25	50	250	0.30	50
CMI160808V82N	0.082±20%	25	50	245	0.30	50
CMI160808VR10	0.10±20%or±10%	25	25	240	0.50	50
CMI160808VR12	0.12±20%or±10%	25	25	205	0.50	50
CMI160808VR15	0.15±20%or±10%	25	25	180	0.60	50
CMI160808VR18	0.18±20%or±10%	25	25	165	0.60	50
CMI160808VR22	0.22±20%or±10%	25	25	150	0.80	50
CMI160808VR27	0.27±20%or±10%	25	25	136	0.80	50
CMI160808VR33	0.33±20%or±10%	25	25	125	0.80	35
CMI160808VR39	0.39±20%or±10%	25	25	110	0.85	35
CMI160808VR47	0.47±20%or±10%	25	25	105	1.00	35
CMI160808VR56	0.56±20%or±10%	25	25	95	1.35	35
CMI160808VR68	0.68±20%or±10%	25	25	90	1.55	35
CMI160808VR82	0.82±20%or±10%	25	25	85	1.70	35
CMI160808U1R0	1.0±20%or±10%	15	10	75	2.10	25
CMI160808U1R2	1.2±20%or±10%	15	10	65	0.60	25
CMI160808U1R5	1.5±20%or±10%	15	10	60	0.80	25
CMI160808U1R8	1.8±20%or±10%	20	10	55	0.95	25
CMI160808U2R2	2.2±20%or±10%	20	10	50	1.15	15
CMI160808U2R7	2.7±20%or±10%	20	10	45	1.35	15
CMI160808U3R3	3.3±20%or±10%	20	10	40	1.55	15
CMI160808U3R9	3.9±20%or±10%	20	10	35	1.70	15
CMI160808U4R7	4.7±20%or±10%	20	10	33	2.10	15

201209 · 201212 SERIES

Part No.	Inductance (μH)	Q Min.	L,Q Test Frequency (MHz)	Self-Resonant Frequency Min. Nominal (MHz)		DC Resistance Max. Nominal (Ω)		Rated Current Max. (mA)
CMI201209V47N	0.047±20%	35	50	320	400	0.20	0.11	300
CMI201209V68N	0.068±20%	35	50	280	350	0.20	0.11	300
CMI201209V82N	0.082±20%	35	50	255	320	0.20	0.11	300
CMI201209VR10	0.10±20%or±10%	35	25	235	300	0.30	0.16	250
CMI201209VR12	0.12±20%or±10%	35	25	220	280	0.30	0.16	250
CMI201209VR15	0.15±20%or±10%	35	25	200	250	0.40	0.21	250
CMI201209VR18	0.18±20%or±10%	35	25	185	230	0.40	0.21	250
CMI201209VR22	0.22±20%or±10%	35	25	170	220	0.50	0.26	250
CMI201209VR27	0.27±20%or±10%	35	25	150	280	0.50	0.26	250
CMI201209VR33	0.33±20%or±10%	35	25	145	180	0.55	0.31	250
CMI201209VR39	0.39±20%or±10%	35	25	135	170	0.65	0.36	200
CMI201209VR47	0.47±20%or±10%	35	25	125	160	0.65	0.36	200
CMI201209VR56	0.56±20%or±10%	35	25	115	150	0.75	0.41	150
CMI201209VR68	0.68±20%or±10%	35	25	105	135	0.80	0.46	150
CMI201209VR82	0.82±20%or±10%	35	25	100	125	1.00	0.56	150
CMI201209U1R0	1.0±20%or±10%	25	10	75	105	0.40	0.21	50
CMI201209U1R2	1.2±20%or±10%	25	10	65	95	0.50	0.26	50
CMI201209U1R5	1.5±20%or±10%	30	10	60	85	0.50	0.26	50
CMI201212U1R8	1.8±20%or±10%	30	10	55	78	0.60	0.31	50
CMI201212U2R2	2.2±20%or±10%	30	10	50	70	0.65	0.36	30
CMI201212U2R7	2.7±20%or±10%	30	10	45	64	0.75	0.41	30
CMI201212U3R3	3.3±20%or±10%	40	10	41	58	0.80	0.46	30
CMI201212U3R9	3.9±20%or±10%	40	10	38	53	0.90	0.51	30
CMI201212U4R7	4.7±20%or±10%	40	10	35	58	1.00	0.56	30
CMI201212X5R6	5.6±20%or±10%	25	4	32	44	0.90	0.51	15
CMI201212X6R8	6.8±20%or±10%	25	4	29	40	1.00	0.356	15
CMI201212X8R2	8.2±20%or±10%	25	4	26	36	1.10	0.61	15
CMI201212X100	10.0±20%or±10%	20	2	24	33	1.15	0.66	15
CMI201212X120	12.0±20%or±10%	20	2	22	30	1.25	0.71	15
CMI201212J150	15.0±20%or±10%	20	1	19	27	0.80	0.46	5
CMI201212J180	18.0±20%or±10%	20	1	18	25	0.90	0.51	5
CMI201212J220	22.0±20%or±10%	20	1	16	22	1.10	0.61	5

FERRITE MULTILAYER CHIP INDUCTOR

321611 SERIES

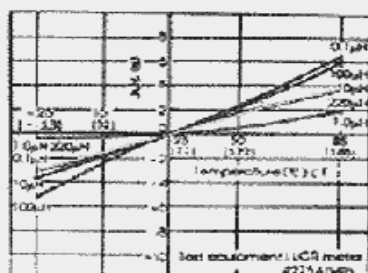
Part No.	Inductance (μ H)	Q Min.	L,Q Test Frequency (MHz)	Self-Resonant Frequency Min. Nominal(MHz)		DC Resistance Max. Nominal(Ω)		Rated Current Max. (mA)
CMI321611V47N	0.047 $\pm$ 20%	40	50	320	400	0.15	0.08	300
CMI321611V68N	0.068 $\pm$ 20%	40	50	280	330	0.25	0.13	300
CMI321611VR10	0.10 $\pm$ 20%or $\pm$ 10%	40	25	235	280	0.25	0.13	250
CMI321611VR12	0.12 $\pm$ 20%or $\pm$ 10%	40	25	220	260	0.30	0.18	250
CMI321611VR15	0.15 $\pm$ 20%or $\pm$ 10%	40	25	200	240	0.30	0.18	250
CMI321611VR18	0.18 $\pm$ 20%or $\pm$ 10%	40	25	185	220	0.40	0.23	250
CMI321611VR22	0.22 $\pm$ 20%or $\pm$ 10%	40	25	170	200	0.40	0.23	250
CMI321611VR27	0.27 $\pm$ 20%or $\pm$ 10%	40	25	150	180	0.50	0.28	250
CMI321611VR33	0.33 $\pm$ 20%or $\pm$ 10%	40	25	145	170	0.60	0.28	250
CMI321611VR39	0.39 $\pm$ 20%or $\pm$ 10%	40	25	135	160	0.50	0.34	200
CMI321611VR47	0.47 $\pm$ 20%or $\pm$ 10%	40	25	125	145	0.60	0.28	200
CMI321611VR56	0.56 $\pm$ 20%or $\pm$ 10%	40	25	115	135	0.70	0.34	150
CMI321611VR68	0.68 $\pm$ 20%or $\pm$ 10%	40	25	105	125	0.80	0.39	150
CMI321611VR82	0.82 $\pm$ 20%or $\pm$ 10%	40	25	100	115	0.90	0.44	150
CMI321611U1R0	1.0 $\pm$ 20%or $\pm$ 10%	40	10	75	90	0.40	0.39	100
CMI321611U1R2	1.2 $\pm$ 20%or $\pm$ 10%	40	10	65	80	0.50	0.44	100
CMI321611U1R5	1.5 $\pm$ 20%or $\pm$ 10%	40	10	60	70	0.50	0.50	50
CMI321611U1R8	1.8 $\pm$ 20%or $\pm$ 10%	40	10	55	66	0.50	0.23	50
CMI321611U2R2	2.2 $\pm$ 20%or $\pm$ 10%	40	10	50	58	0.60	0.28	50
CMI321611U2R7	2.7 $\pm$ 20%or $\pm$ 10%	40	10	45	53	0.60	0.28	50
CMI321611U3R3	3.3 $\pm$ 20%or $\pm$ 10%	40	10	41	49	0.70	0.28	50
CMI321611U3R9	3.9 $\pm$ 20%or $\pm$ 10%	40	10	38	45	0.80	0.34	50
CMI321611U4R7	4.7 $\pm$ 20%or $\pm$ 10%	40	10	35	41	0.90	0.34	50
CMI321611U5R6	5.6 $\pm$ 20%or $\pm$ 10%	40	4	32	38	0.70	0.39	25
CMI321611U6R8	6.8 $\pm$ 20%or $\pm$ 10%	40	4	29	34	0.80	0.44	25
CMI321611U8R2	8.2 $\pm$ 20%or $\pm$ 10%	40	4	26	31	0.90	0.50	25
CMI321611X100	10.0 $\pm$ 20%or $\pm$ 10%	25	2	24	28	1.00	0.55	25
CMI321611X120	12.0 $\pm$ 20%or $\pm$ 10%	25	2	22	26	1.05	0.60	15
CMI321611X150	15.0 $\pm$ 20%or $\pm$ 10%	25	1	19	23	0.70	0.39	5
CMI321611X180	18.0 $\pm$ 20%or $\pm$ 10%	25	1	18	21	0.70	0.39	5
CMI321611X220	22.0 $\pm$ 20%or $\pm$ 10%	25	1	16	19	0.90	0.50	5
CMI321611X270	27.0 $\pm$ 20%or $\pm$ 10%	25	1	14	17	0.90	0.50	5
CMI321611X330	33.0 $\pm$ 20%or $\pm$ 10%	25	0.4	13	16	1.05	0.60	5

FERRITE MULTILAYER CHIP INDUCTOR

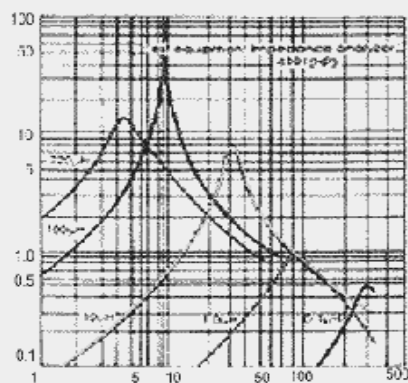
TYPICAL CHARACTERISTICS

CM1201209, CM1201212 SERIES

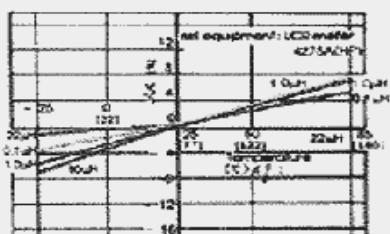
电感量温度特性 Inductance VS. Temperature



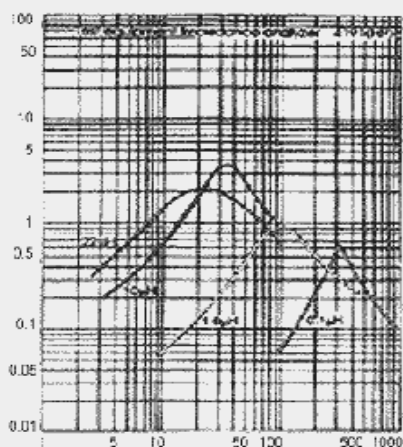
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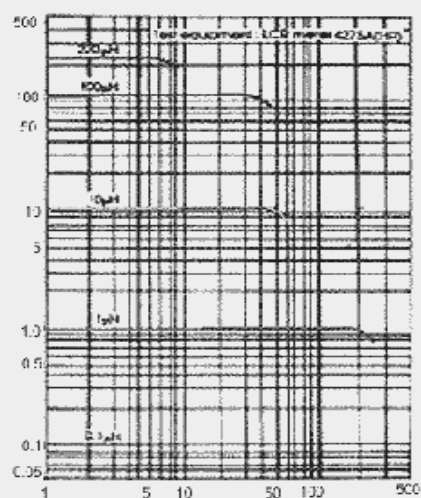
电感量温度特性 Inductance VS. Temperature



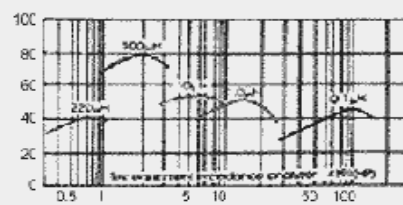
阻抗频率特性 Impedance VS. Frequency



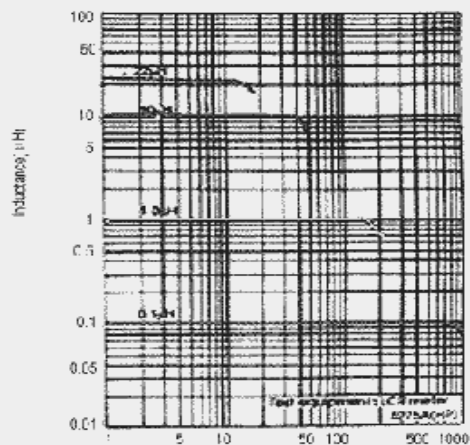
电感直流偏特性 Inductance VS. DC Bias



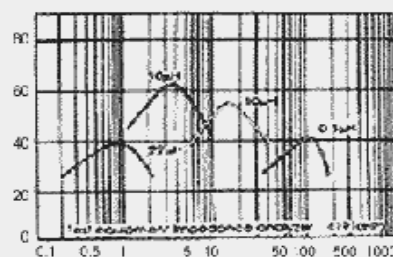
品质因数特性 Q Value VS. Frequency



电感量直流偏特性 Inductance VS. DC Bias

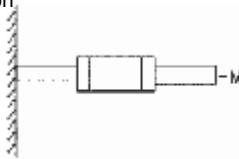
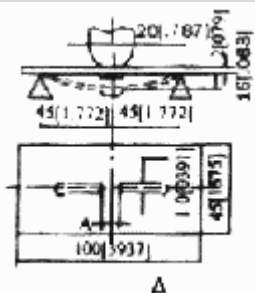
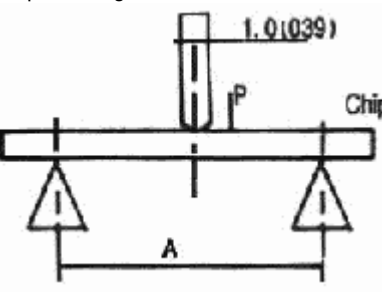


品质因数特性 Q Value VS. Frequency



FERRITE MULTILAYER CHIP INDUCTOR

RELIABILITY TEST CONDITIONS

Item	Specifications	Test Methods												
Temperature Operating Ranges	-25°C~+85°C													
Storage Temperature Range	-40°C+85°C -0°C~+60°C (Tape & Reel)													
Solder ability	More than 90% of termination Should be covered with new solder	Preheat: 120°C+150°C for 60s Solder sn: pb=63:73 Temperature: 230°C±5°C Flux: rosin Duration: 3±1s												
Resistance to Soldering heat	More than 75% of termination Should be covered with solder	Preheat: 120°C+150°C for 60s Solder sn: pb=63:73 Temperature: 300°C±5°C Flux: rosin Duration: 10±0.5s												
Terminal Strength	The terminal and body should be no damage	Applied specified pull strength in axial direction <table border="1"> <thead> <tr> <th>Size</th><th>Pull Strength (N)(kg)</th><th>Time</th></tr> </thead> <tbody> <tr> <td>1608</td><td>5.9(0.6)</td><td>30±5</td></tr> <tr> <td>2012</td><td>9.8(1.0)</td><td>30±5</td></tr> <tr> <td>3216</td><td>9.8(1.0)</td><td>30±5</td></tr> </tbody> </table> 	Size	Pull Strength (N)(kg)	Time	1608	5.9(0.6)	30±5	2012	9.8(1.0)	30±5	3216	9.8(1.0)	30±5
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2012	9.8(1.0)	30±5												
3216	9.8(1.0)	30±5												
Flexure Strength	No mechanical damage should be noticed	When the board curve to 2mm(0.079 inches) 0.7(0.028) (1608) 1.0(0.039) (2012) 2.0(0.039) (3216) Dimensions in mm (inches) 												
Bending Strength	The ferrite body should not be damaged	Applied specified pull strength in axial direction <table border="1"> <thead> <tr> <th>Size</th><th>A(mm) (inches)</th><th>Pn (kg)</th></tr> </thead> <tbody> <tr> <td>1608</td><td>100(.039)</td><td>4.9(0.5)</td></tr> <tr> <td>2012</td><td>1.40(.055)</td><td>9.8(1.0)</td></tr> <tr> <td>3216</td><td>2.0(0.079)</td><td>9.8(1.0)</td></tr> </tbody> </table> 	Size	A(mm) (inches)	Pn (kg)	1608	100(.039)	4.9(0.5)	2012	1.40(.055)	9.8(1.0)	3216	2.0(0.079)	9.8(1.0)
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Thermal Shock (Temperature Cycling)	No mechanical damage should be noticed inductance and Q value should be within ±10% and ±30% of the value respectively.	Temperature:-25°C~+85°C 5 cycles 30 min for each												
Humidity Resistance		Placed at 60°C 90%RH applied DC 200mA for 500hrs and measured at ambient temperature												
Drop		Drop 10 times on a concrete floor from a height of 1m												
Vibration		Frequency:10~50Hz Amplitude modulation:1.55mm Direction and time: X、Y and z direction for 2hrs each												
Solubility Resistance		Solvent: trichloroethylene Cleaning: Ultrasonic washer Duration:3min												